High Efficiency Off-Line CC/CV Switch

FEATURES

- Constant-Current (CC) and Constant-Voltage (CV) with Primary Side Control
- Proprietary technology enabling high efficiency and fast dynamic response
- No audible noise over entire operating range
- Built-in power MOS
- > Built-in Cable Compensation
- Built-in Line Compensation
- Primary-side feedback eliminates opto-coupler and TL431
- > Cycle-by-Cycle Current Limiting
- > Over Temperature Protection
- > VCC Over Voltage Protection
- > CV Open-loop Protection
- Excellent capacitive loading start-up performance

TYPICAL APPLICATION

- Adapter/Charger for Cell/Cordless Phones,
 PDAs, MP3 and Other Portable Apparatus
- Standby and Auxiliary Power Supplies
 Set Top Boxes (STB)
- > Adapter for ADSL / WiFi Wireless
- > AC/DC LED Driver applications

DESCRIPTION

The FT838MBD/FT838MDD controller device is optimized for high-performance, low power switching mode power supply applications. The FT838MBD/FT838MDD facilitates CC/CV charger design by eliminating an opto-coupler and TL431. Its highly integrated functions such as Under Voltage Lockout (UVLO), Leading Edge Blanking (LEB) and built-in cable compensation offer the users a high efficiency and low cost solution for AC/DC power applications.

Power supplies built with FT838MBD/FT838MDD can achieve both high average efficiency, fast dynamic load response and super low standby power.

Furthermore, FT838MBD/FT838MDD features fruitful protections like Open Circuit Protection and Over Temperature Protection to eliminate the external protection circuits and provide reliable operations. FT838MBD/FT838MDD is available in DIP8 package.

TYPICAL APPLICATION CIRCUIT



Figure 1: FT838MBD/838MDD Typical Application Circuit

ABSOLUTE MAXIMUM RATINGS

FB to GND	0.3V to +7V
CS to GND	-0.3V to +7V
VCC to GND	0.3V to +30V
C to GND	0.3V to +700V
Operating Temperature Range	40℃ to +125℃
Junction Temperature	40℃ to +150℃
Storage Temperature Range	60℃ to +150℃
ESD Protection HBM	
ESD Protection MM	200V

*Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



PIN CONFIGURATION





TERMINAL DEFINITION

Pin	Name	Description
1	CS	Primary current sense
2	FB	Output voltage feedback pin
3	GND	Ground.
4	VCC	Supply voltage
5	NC	No connection
6	NC	No connection
7	D	The drain of the power MOS. This pin is connected to the primary lead of the
8		transformer

Table 1

ORDERING INFORMATION



FT838MBD1/FT838MDD1

Device	DESIGNATOR	SYMBOL	Options		
		0	Cable Comp = 0%		
FT838MBD①	1	1	Cable Comp = 3%		
FT838MDD1		2	Cable Comp = 6%		
		3	Cable Comp = 9%		

Table 2

MARKING RULE



Figure 3: Marking Rule

(1): Represents Version (0, 1, 2 or 3)

2345: for internal reference



Block Diagram



Figure 4: FT838MBD/838MDD Block Diagram

ELECTRICAL CHARACTERISTICS

(For typical values Tj=25°C, Vcc=12V, unless otherwise noted)

Characte	ristic	Symbol	Min	Тур	Max	Unit
Current Sense		· · · · · ·				
Maximum Current Th	reshold	Vcs_max	535	552	575	mV
Leading Edge Blanking Duration		Tleb	350	400	450	ns
Propagation Delay		Trid			200	20
(OUT=1.0nF to GND))	Tpd			200	ns
Feedback Section						
Feedback Voltage Th	ireshold	Vfb	2.856	2.9	2.944	V
CCM protection Three	shold Level	Vcp		100		mV
Supply Section					XIC	
Start Up Threshold V	oltage	Vcc_on	15.5	16.2	17.5	V
Under Voltage Locko	ut Voltage	Vcc_off	5.2	5.5	6.0	V
VCC Start Up Curren	t	Istart_up		2	5	uA
Operating Current		lop	0.4	0.5	0.7	mA
Protection Section		· ·			-	-
Feedback Loop Oper	Protection	lfb_open	90	115	140	uA
VCC Over Voltage Pr	rotection	Vcc_OVP	26	27	28	V
Over Temperature Pr	otection	T_OTP		145		°C
Compensation				•		
Line Compensation (lfb=1mA)	Vline	25	33	40	mV
	0			0		
Cable	1			3		0/
compensation	2	Kcab		6		%
	3			9		
Power MOS Section	(FT838MBD)					
Characteristic	Symbol	Test condition	Min	Тур	Мах	Unit
Static drain-source on-resistance	R _{DS_ON}	V _{GS} =10V, I _{DS} =0.5A		5.5		Ω
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V, I _{DS} =250uA	650			V
Drain-source leakage current	I _{DSS}	V _{GS} =0V, V _{DS} =650V			10	uA
Maximum Drain Current	I _{DMAX}	Vd=4V	0.6	0.7		A
Power MOS Section	(FT838MDD)				1	
Static drain-source on-resistance	R _{DS_ON}	V _{GS} =10V, I _{DS} =0.5A		2.6		Ω
Drain-source	BV _{DSS}	V _{GS} =0V,	650			V

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Preliminary FT838MBD/838MDD

breakdown voltage		I _{DS} =250uA				
Drain-source		V _{GS} =0V,			10	uA
leakage current	I _{DSS}	V_{DS} =650V			10	uA
Maximum Drain	1	Vd=3V	1.0	1.1		۸
Current	IDMAX	vu=3v	1.0	1.1		A

Table 3

FUNCTIONAL DESCRIPTION

Operating Description

FT838MBD/FT838MDD is a cost effective and high-performance AC-DC power supply controller for off-line low power AC-DC applications including battery chargers, adaptors and LED lighting. The constant voltage (CV) and constant current (CC) control are achieved accurately without the secondary feedback circuit.

Start up Control

Start-up current of FT838MBD/838MDD is very low so that a start-up resistor with high resistance and low-wattage is allowed to supply the start-up power for the controller. The large value startup resistor minimizes the power loss in operations and allows quick start up. With a special fast startup technology, FT838MBD/FT838MDD starts up easily in capacitive loading applications.

Operating current

The operating current of FT838MBD/FT838MDD is as low as 500uA. Good efficiency is achieved with the low operating current. Low operating current also reduces the Vcc hold-up capacitance requirement.

Constant voltage (CV) and constant current (CC) Operation

The FT838MBD/FT838MDD can accurately achieve CV/CC characteristic output without secondary side voltage and current-feedback circuits. It operates in CV mode to regulate the output voltage by capturing the auxiliary winding feedback voltage at FB pin. The auxiliary winding feedback voltage is proportional to secondary winding, so it provides controller the feedback signal from secondary side and achieves constant-voltage output. In CC mode, the controller detects the secondary discharger peak current and the discharger time, which determines the off-time of the base driver to make the output average current constant.

Primary peak current modulation

Primary peak current is constant at constant current mode. And primary peak current is modulated at constant voltage mode for the purposes of good dynamic load response and no audible noise over entire operating range. According to the output loading current the current threshold voltage is modulated from 0.55V to 0.27V. The current threshold voltage is 0.55V at rated load and 0.27V at light load.

Leading edge blanking

Each time the power MOS transistor is switched on, a turn-on spike occurs at the sense resistor. To avoid premature termination of the switching pulse, a 400ns leading edge blanking time is built in. Conventional RC filtering can therefore be omitted. During this blanking period, the current limit comparator is disabling and cannot switch off the base driver.

Under voltage lockout (UVLO)

FT838MBD/FT838MDD turn-on Vcc_on and turn-off Vcc_off are 16.2 V and 5.5 V, respectively. During start-up, the hold-up capacitor must be charged to 16.2V through the start-up resistor. The hold-up



capacitor continues to supply Vcc until power can be delivered from the auxiliary winding of the transformer. Vcc must not drop below 5.5 V during this start-up process. This UVLO hysteresis window ensures that hold-up capacitor is sufficient to supply Vcc during start-up.

Protection control

With rich protection features of FT838MBD/FT838MDD, excellent power supply system reliability can be achieved. The protection features include cycle by cycle current limiting, Vcc over voltage protection and clamp, over temperature protection, feedback loop open circuit protection and Vcc under voltage lockout, etc.

Integrated MOS

Power MOS is integrated in FT838MBD/FT838MDD for low cost and/or space limited applications, respectively.

Output cable compensation

The output cable compensation provides a constant output voltage at the end of the cable over the entire load range in constant voltage mode. As the converter load increases from no-load to the peak current load, the voltage drop introduced across the output cable is compensated by increasing the feedback pin reference voltage.

PACKAGE INFORMATION

DIP8 Package







Symbol	Dimensions In Millimeters		Dimensions In Inches		
Cymson	Min	Мах	Min	Max	
А	3.710	4.310	0.146	0.170	
A1	0.510		0.020		
A2	3.200	3.600	0.126	0.142	
В	0.380	0.570	0.015	0.022	
B1	1.524 (BSC)		0.060 (BSC)		
С	0.204	0.360	0.008	0.014	
D	9.000	9.400	0.354	0.370	
E	6.200	6.600	0.244	0.260	
E1	7.320	7.920	0.288	0.312	
е	2.540 (BSC)		0.100 (BSC)		
L	3.000	3.600	0.118	0.142	
E2	8.400	9.000	0.331	0.354	

Fremont Micro Devices (SZ) Limited

#5-8, 10/F, Changhong Building, Ke-Ji Nan 12 Road, Nanshan District, Shenzhen, Guangdong 518057 Tel: (86 755) 86117811 Fax: (86 755) 86117810

Fremont Micro Devices (Hong Kong) Limited

#16, 16/F, Blk B, Veristrong Industrial Centre, 34-36 Au Pui Wan Street, Fotan, Shatin, Hong Kong Tel: (852) 27811186 Fax: (852) 27811144

Fremont Micro Devices (USA), Inc.

42982 Osgood Road Fremont, CA 94539 Tel: (1-510) 668-1321 Fax: (1-510) 226-9918

Web Site: http://www.fremontmicro.com/

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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный) **Факс:** 8 (812) 320-02-42 **Электронная почта:** <u>org@eplast1.ru</u> **Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.